

rfmd.com

SGA-6389(Z)

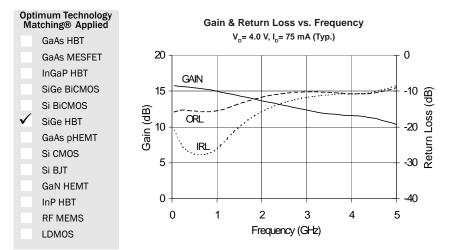
DC to 4500 MHz, CASCADABLE SiGe HBT MMIC AMPLIFIER

Package: SOT-89



Product Description

The SGA-6389 is a high performance SiGe HBT MMIC Amplifier. A Darlington configuration featuring one-micron emitters provides high $F_{\rm T}$ and excellent thermal performance. The heterojunction increases breakdown voltage and minimizes leakage current between junctions. Cancellation of emitter junction non-linearities results in higher suppression of intermodulation products. Only two DC-blocking capacitors, a bias resistor, and an optional RF choke are required for operation.



Features

- Available in RFMD Green, RoHS Compliant, and Pb-Free (Z Part Number)
- Broadband Operation: DC to 4500MHz
- Cascadable 50Ω
- Operates from Single Supply
- Low Thermal Resistance Package

Applications

- PA Driver Amplifier
- Cellular, PCS, GSM, UMTS
- IF Amplifier
- Wireless Data, Satellite

Parameter	Specification			Unit	Condition
	Min.	Тур.	Max.	Unit	Condition
Small Signal Gain	14.1	15.5	17.3	dB	850MHz
		14.0		dB	1950MHz
		13.3		dB	2400MHz
Output Power at 1dB Compression		20.2		dBm	850MHz
		18.9		dBm	1950MHz
Output Third Intercept Point		35.2		dBm	850MHz
		32.6		dBm	1950MHz
Bandwidth Determined by Return Loss		4500		MHz	>10dB
Input Return Loss		16.0		dB	1950MHz
Output Return Loss		11.9		dB	1950MHz
Noise Figure		4.2		dB	1950MHz
Device Operating Voltage	4.6	4.9	5.4	V	
Device Operating Current	72	80	88	mA	
Thermal Resistance (Junction - Lead)		97		°C/W	

Test Conditions: $V_S = 8V$, $I_D = 80$ mA Typ., OIP₃ Tone Spacing=1MHz, P_{OUT} per tone=0dBm, $R_{BIAS} = 39\Omega$, $T_L = 25$ °C, $Z_S = Z_L = 50\Omega$

SGA-6389(Z)



Absolute Maximum Ratings

Parameter	Rating	Unit			
Max Device Current (I _D)	160	mA			
Max Device Voltage (V _D)	7	V			
Max RF Input Power	+18	dBm			
Max Junction Temp (T _J)	+150	°C			
Operating Temp Range (T _L)	-40 to +85	°C			
Max Storage Temp	+150	°C			
Moisture Sensitivity Level	MSL 2				

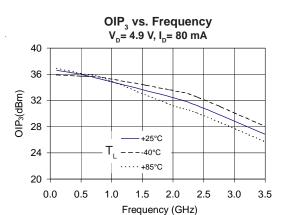
Operation of this device beyond any one of these limits may cause permanent damage. For reliable continuous operation, the device voltage and current must not exceed the maximum operating values specified in the table on page one. Bias Conditions should also satisfy the following expression:

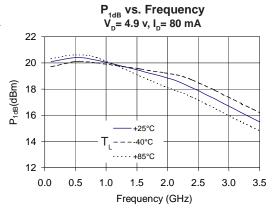
 $I_D V_D < (T_J - T_L) / R_{TH}$, j-I

Typical Performance at Key Operating Frequencies

Parameter	Unit	100	500	850	1950	2400	3500
		MHz	MHz	MHz	MHz	MHz	MHz
Small Signal Gain	dB	15.7	15.6	15.5	14.0	13.3	12.0
Output Third Order Intercept Point	dBm	36.6	36.0	35.2	32.6	31.2	26.8
Output Power at 1dB Compression	dBm	20.1	20.4	20.2	18.9	18.1	15.5
Input Return Loss	dB	22.3	27.5	27.4	16.0	13.7	11.0
Output Return Loss	dB	14.7	14.5	14.8	11.9	10.8	10.4
Reverse Isolation	dB	20.4	20.2	20.3	20.1	19.7	18.2
Noise Figure	dB	4.0	3.7	3.8	4.2	4.4	4.8

Test Conditions: $V_S = 8V$, $I_D = 80$ mA Typ., OIP₃ Tone Spacing = 1 MHz, P_{OUT} per tone = 0 dBm, $R_{BIAS} = 39\Omega$, $T_L = 25$ °C, $Z_S = Z_L = 50\Omega$





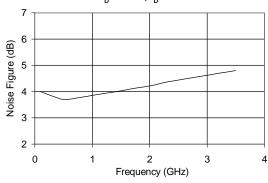
Caution! ESD sensitive device.

Exceeding any one or a combination of the Absolute Maximum Rating conditions may cause permanent damage to the device. Extended application of Absolute Maximum Rating conditions to the device may reduce device reliability. Specified typical perfor-mance or functional operation of the device under Absolute Maximum Rating condi-tions is not implied.

RoHS status based on EUDirective2002/95/EC (at time of this document revision).

The information in this publication is believed to be accurate and reliable. However, no responsibility is assumed by RF Micro Devices, Inc. ("RFMD") for its use, nor for any infringement of patents, or other rights of third parties, resulting from its use. No license is granted by implication or otherwise under any patent or patent rights of RFMD. RFMD reserves the right to change component circuitry, recommended application circuitry and specifications at any time without prior notice.

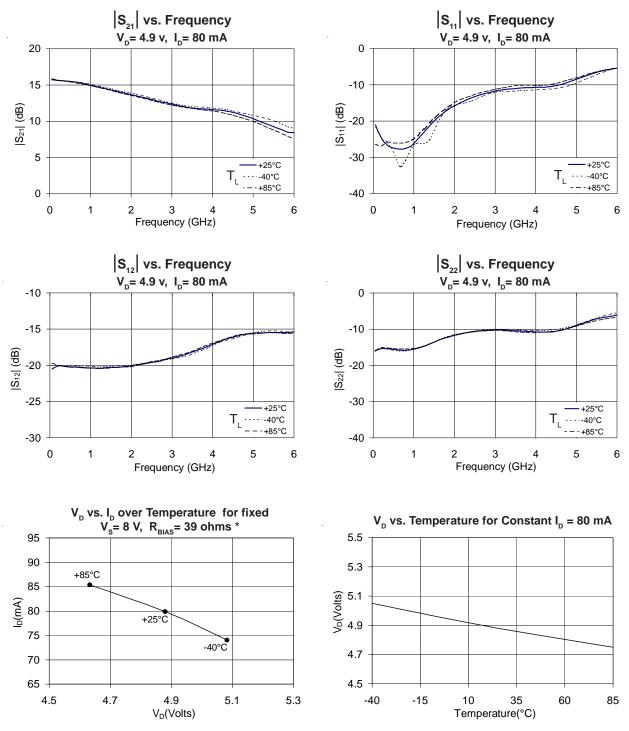
Noise Figure vs. Frequency $V_{p} = 4.9 V, I_{p} = 80 mA$



7628 Thorndike Road, Greensboro, NC 27409-9421 · For sales or technical support, contact RFMD at (+1) 336-678-5570 or sales-support@rfmd.com.

SGA-6389(Z)





* Note: In the applications circuit on page 4, R_{BIAS} compensates for voltage and current variation over temperature.

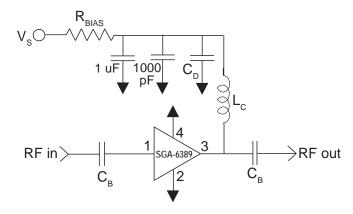
SGA-6389(Z)

RFMD ໜ

rfmd.com

Pin	Function	Description
1	RF IN	RF input pin. This pin requires the use of an external DC-blocking capacitor chosen for the frequency of operation.
2, 4	GND	Connection to ground. For optimum RF performance, use via holes as close to ground leads as possible to reduce lead inductance.
3	RF OUT/BIAS	RF output and bias pin. DC voltage is present on this pin, therefor a DC-blocking capacitor is necessary for proper opera- tion.

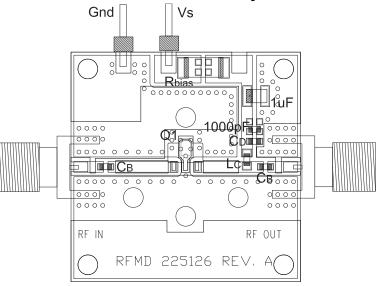
Application Schematic



Reference	Frequency (Mhz)						
Designator	500	850	1950	2400	3500		
C _B	220 pF	100 pF	68 pF	56 pF	39 pF		
C _D	100 pF	68 pF	22 pF	22 pF	15 pF		
L _c	68 nH	33 nH	22 nH	18 nH	15 nH		

Recommended Bias Resistor Values for $I_D = 80$ mA $R_{BIAS} = (V_S - V_D) / I_D$					
Supply Voltage(V _s)	6 V	8 V	10 V	12 V	
R _{BIAS} 13 Ω 39 Ω 62 Ω 91 Ω					
Note: R _{BIAS} provides DC bias stability over temperature.					

Evaluation Board Layout



Mounting Instructions:

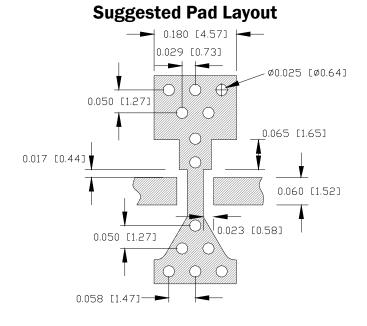
1. Solder the copper pad on the backside of the device package to the ground plane.

2. Use a large ground pad area with many plated through-holes as shown.

3. We recommend 1 or 2 ounce copper. Measurements for this data sheet were made on a 31mil thick FR-4 board with 1 ounce copper on both sides.

rfmd.com

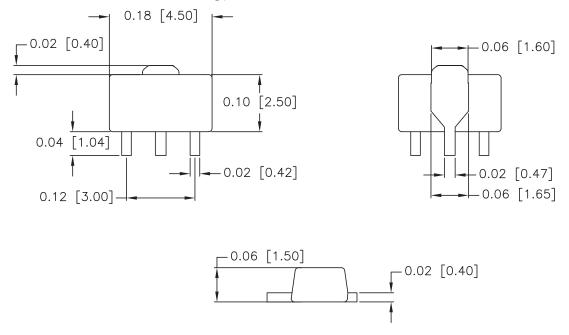




Package Drawing

Dimensions in inches (millimeters)

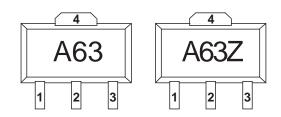
Refer to drawing posted at www.rfmd.com for tolerances.







Part Identification



Alternate marking SGA6389 or SGA6389Z on line 1 with Trace Code on line 2.

Ordering Information

Part Number	Reel Size	Devices/Reel
SGA-6389	13"	3000
SGA-6389Z	13"	3000